

74LVTH125

Low Voltage Quad Buffer with 3-STATE Outputs

General Description

The LVTH125 contains four independent non-inverting buffers with 3-STATE outputs.

These buffers are designed for low-voltage (3.3V) V_{CC} applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH125 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

Features

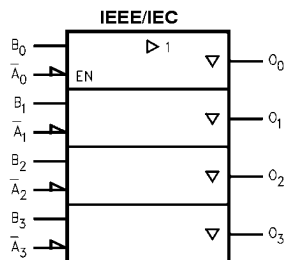
- Input and output interface capability to systems at 5V V_{CC}
- Bus-Hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink $-32\text{ mA}/+64\text{ mA}$
- Functionally compatible with the 74 series 125
- Latch-up performance exceeds 500 mA

Ordering Code:

Order Number	Package Number	Package Description
74LVTH125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow
74LVTH125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

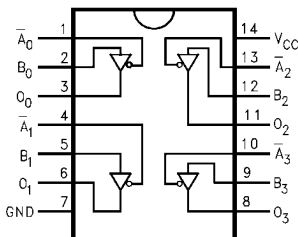
Logic Symbol



Pin Descriptions

Pin Names	Description
$\bar{A}_n, B_n$	Inputs
O_n	3-STATE Outputs

Connection Diagram



Truth Table

Inputs		Output
$\bar{A}_n$	B_n	O_n
L	L	L
L	H	H
H	X	Z

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = HIGH Impedance

Absolute Maximum Ratings(Note 1)

Symbol	Parameter	Value	Conditions	Units
V_{CC}	Supply Voltage	−0.5 to +4.6		V
V_I	DC Input Voltage	−0.5 to +7.0		V
V_O	DC Output Voltage	−0.5 to +7.0	Output in 3-STATE	V
		−0.5 to +7.0	Output in HIGH or LOW State (Note 2)	
I_{IK}	DC Input Diode Current	−50	$V_I < GND$	mA
I_{OK}	DC Output Diode Current	−50	$V_O < GND$	mA
I_O	DC Output Current	64	$V_O > V_{CC}$ Output at HIGH State	mA
		128	$V_O > V_{CC}$ Output at LOW State	
I_{CC}	DC Supply Current per Supply Pin	±64		mA
I_{GND}	DC Ground Current per Ground Pin	±128		mA
T_{STG}	Storage Temperature	−65 to +150		°C

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V_{CC}	Supply Voltage	2.7	3.6	V
V_I	Input Voltage	0	5.5	V
I_{OH}	HIGH Level Output Current		−32	mA
I_{OL}	LOW Level Output Current		64	mA
T_A	Free-Air Operating Temperature	−40	85	°C
$\Delta t/\Delta V$	Input Edge Rate, $V_{IN} = 0.8V-2.0V$, $V_{CC} = 3.0V$	0	10	ns/V

Note 1: Absolute Maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum rated conditions is not implied.

Note 2: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics							
Symbol	Parameter	V _{CC} (V)	T _A = 40°C to +85°C			Units	Conditions
			Min	Typ (Note 3)	Max		
V _{IK}	Input Clamp Diode Voltage	2.7			−1.2	V	I _I = −18 mA
V _{IH}	Input HIGH Voltage	2.7–3.6	2.0			V	V _O ≤ 0.1V or V _O ≥ V _{CC} − 0.1V
V _{IL}	Input LOW Voltage	2.7–3.6			0.8	V	
V _{OH}	Output HIGH Voltage	2.7–3.6	V _{CC} − 0.2			V	I _{OH} = −100 μA
		2.7	2.4				I _{OH} = −8 mA
		3.0	2.0				I _{OH} = −32 mA
V _{OL}	Output LOW Voltage	2.7			0.2	V	I _{OL} = 100 μA
		2.7			0.5		I _{OL} = 24 mA
		3.0			0.4		I _{OL} = 16 mA
		3.0			0.5		I _{OL} = 32 mA
		3.0			0.55		I _{OL} = 64 mA
I _{I(HOLD)}	Bus-Hold Input Minimum Drive	3.0	75			μA	V _I = 0.8V
			−75				V _I = 2.0V
I _{I(OD)}	Bus-Hold Input Over-Drive Current to Change State	3.0	500			μA	(Note 4)
			−500				(Note 5)
I _I	Input Current	3.6			10	μA	V _I = 5.5V
		Control Pins	3.6		±1		V _I = 0V or V _{CC}
		Data Pins	3.6		−5		V _I = 0V
					1		V _I = V _{CC}
I _{OFF}	Power Off Leakage Current	0			±100	μA	0V ≤ V _I or V _O ≤ 5.5V
I _{PU/PD}	Power up/down 3-STATE Output Current	0–1.5V			±100	μA	V _O = 0.5V to 3.0V V _I = GND or V _{CC}
I _{OZL}	3-STATE Output Leakage Current	3.6			−5	μA	V _O = 0.5V
I _{OZH}	3-STATE Output Leakage Current	3.6			5	μA	V _O = 3.0V
I _{OZH+}	3-STATE Output Leakage Current	3.6			10	μA	V _{CC} < V _O ≤ 5.5V
I _{CCH}	Power Supply Current	3.6			0.19	mA	Outputs HIGH
I _{CCL}	Power Supply Current	3.6			5	mA	Outputs LOW
I _{CCZ}	Power Supply Current	3.6			0.19	mA	Outputs Disabled
I _{CCZ+}	Power Supply Current	3.6			0.19	mA	V _{CC} ≤ V _O ≤ 5.5V Outputs Disabled
ΔI _{CC}	Increase in Power Supply Current (Note 6)	3.6			0.2	mA	One Input at V _{CC} − 0.6V Other Inputs at V _{CC} or GND

Note 3: All typical values are at V_{CC} = 3.3V, T_A = 25°C.

Note 4: An external driver must source at least the specified current to switch from LOW to HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH to LOW.

Note 6: This is the increase in supply current for each input that is at the specified voltage level rather than V_{CC} or GND.

Dynamic Switching Characteristics (Note 7)

Symbol	Parameter	V _{CC} (V)	T _A = 25°C			Units	Conditions C _L = 50 pF, R _L = 500Ω
			Min	Typ	Max		
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3		0.8		V	(Note 8)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3		−0.8		V	(Note 8)

Note 7: Characterized in SOIC package. Guaranteed parameter, but not tested.

Note 8: Max number of outputs defined as (n). n−1 data inputs are driven 0V to 3V. Output under test held LOW.

AC Electrical Characteristics

Symbol	Parameter	T _A = -40°C to +85°C C _L = 50 pF, R _L = 500Ω					Units
		V _{CC} = 3.3V ±0.3V			V _{CC} = 2.7V		
		Min	Typ (Note 9)	Max	Min	Max	
t _{PLH}	Propagation Delay Data to Output	1.0		3.5	1.0	4.5	ns
t _{PHL}		1.0		3.9	1.0	4.9	
t _{PZH}	Output Enable Time	1.0		4.0	1.0	5.5	ns
t _{PZL}		1.1		4.0	1.1	5.4	
t _{PHZ}	Output Disable Time	1.5		4.5	1.5	5.7	ns
t _{PLZ}		1.3		4.5	1.3	4.0	
t _{OSHL}	Output to Output Skew (Note 10)			1.0		1.0	ns
t _{OSLH}							

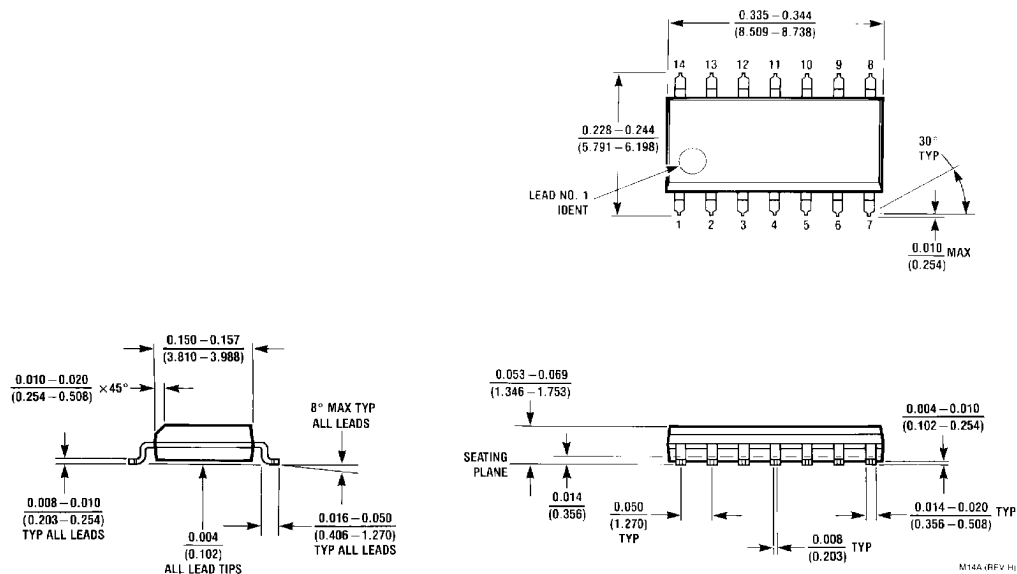
Note 9: All typical values are at $V_{CC} = 3.3V$, $T_A = 25^{\circ}\text{C}$.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

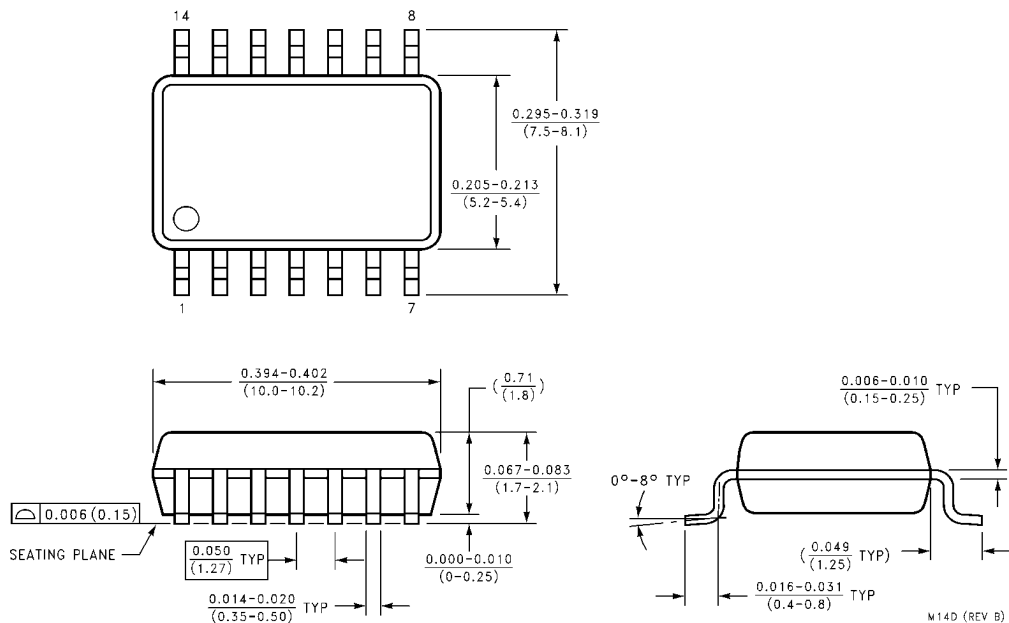
Capacitance (Note 11)

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = 0V, V_I = 0V \text{ or } V_{CC}$	4	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.0V, V_O = 0V \text{ or } V_{CC}$	8	pF

Note 11: Capacitance is measured at frequency $f = 1 \text{ MHz}$, per MIL-STD-883B, Method 3012.

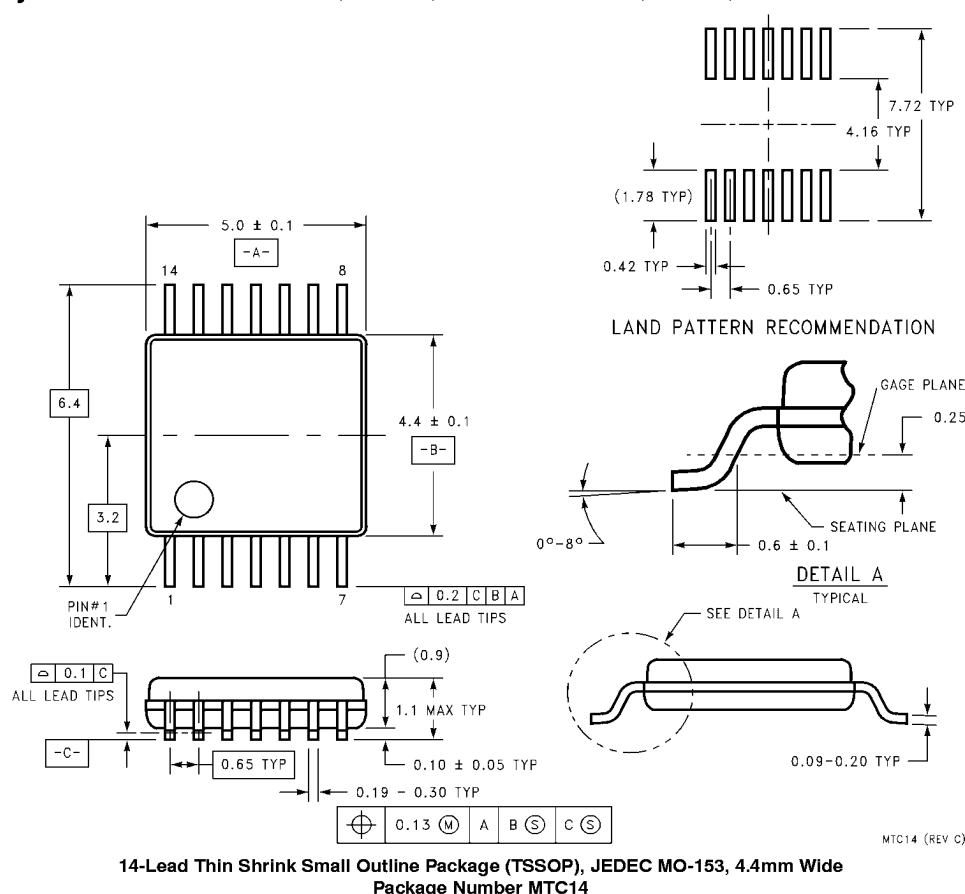
Physical Dimensions inches (millimeters) unless otherwise noted

14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow Package Number M14A



14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide Package Number M14D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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